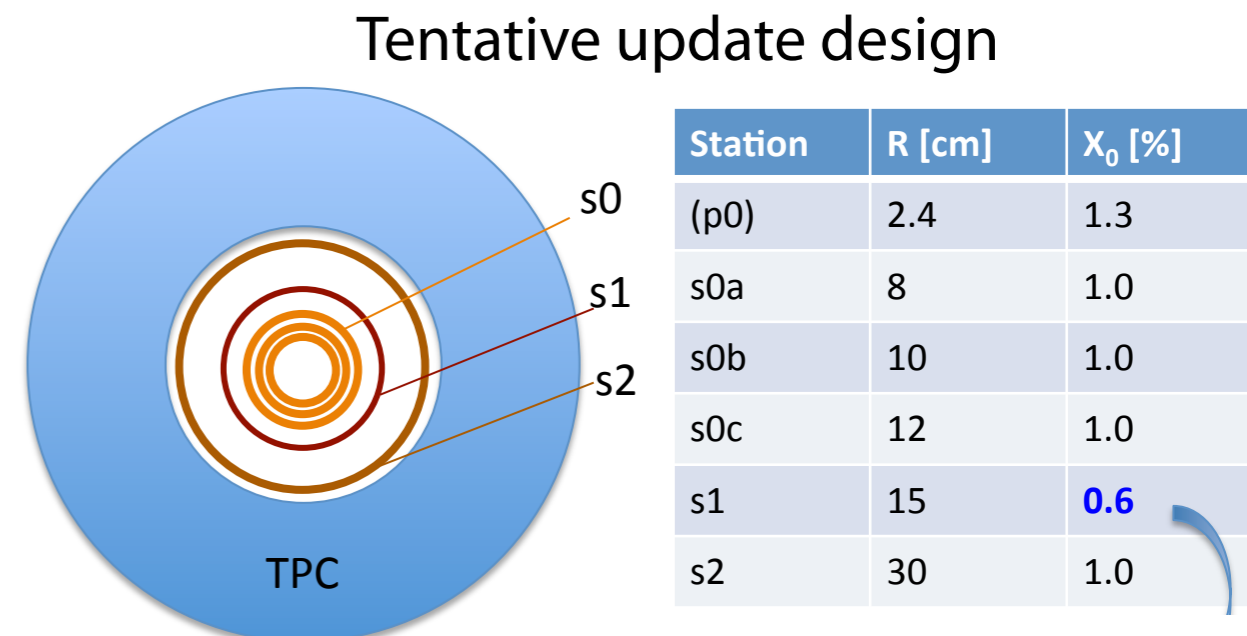


# Upsilon mass resolution in each Si tracker configuration

G. Mitsuka (RBRC)

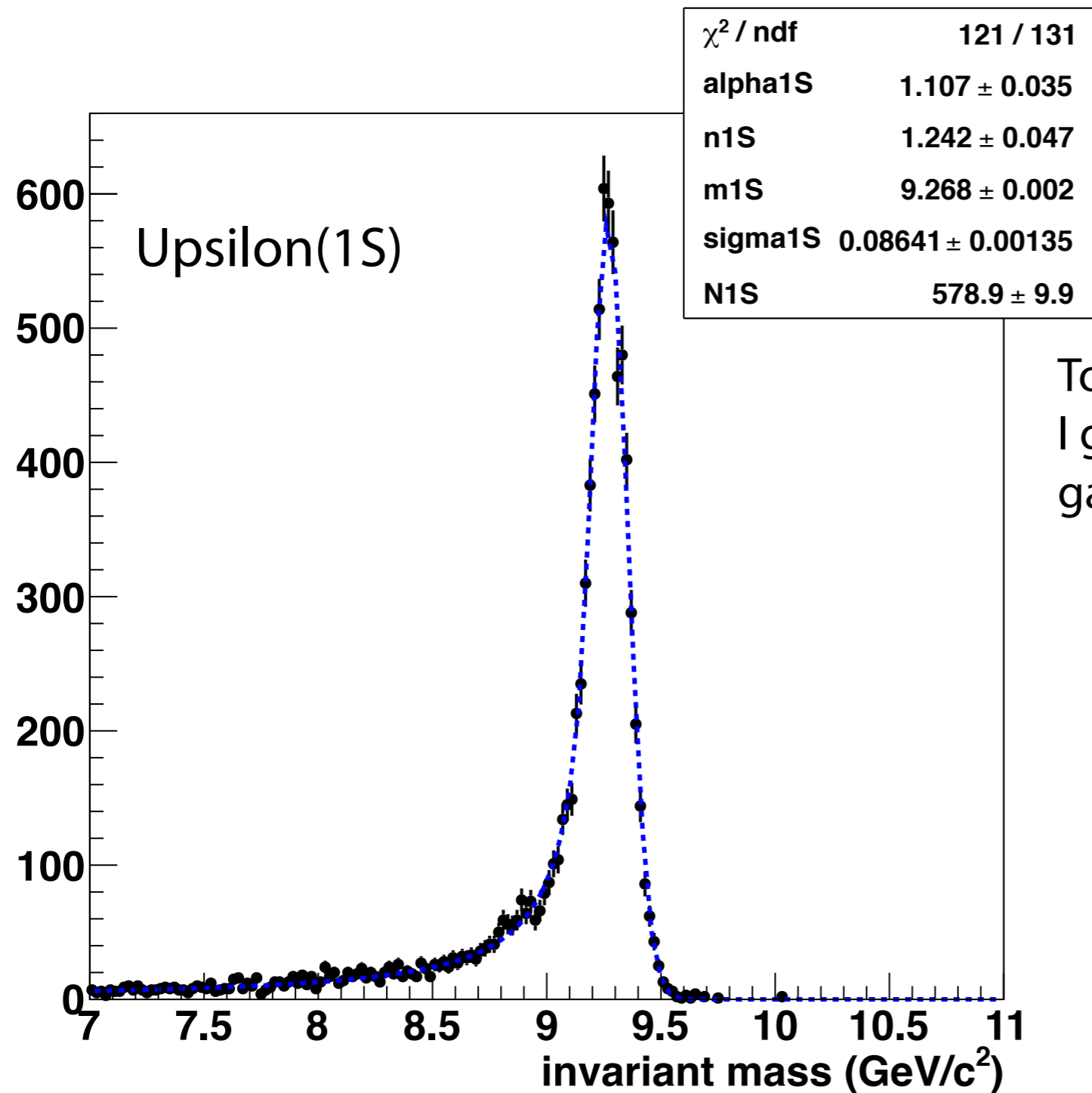
sPHENIX tracker meeting  
April 29, 2016

# Simulation methodology



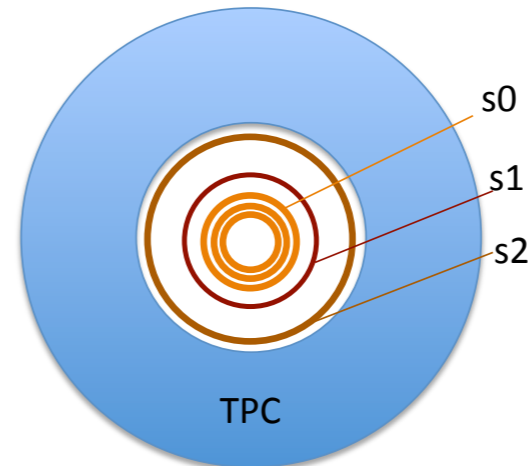
- sPHENIX Geant4 simulation is used.
- Silicon pixel (P0) and silicon-strip tracker (S0, S1, S2) follow cylinder geometry instead of realistic plane geometry. The pixel layer P1 is not taken into account.
- Ganging at the S1 and S2 stations are off. Here we assume the ganging effects can be perfectly eliminated in offline analyses.
- I think Bremsstrahlung in  $Upsilon \rightarrow e^+e^-$  decay, namely  $Upsilon \rightarrow e^+e^-\gamma$ , is not implemented in the simulation framework.

# Ref. configuration (same as C&S review)



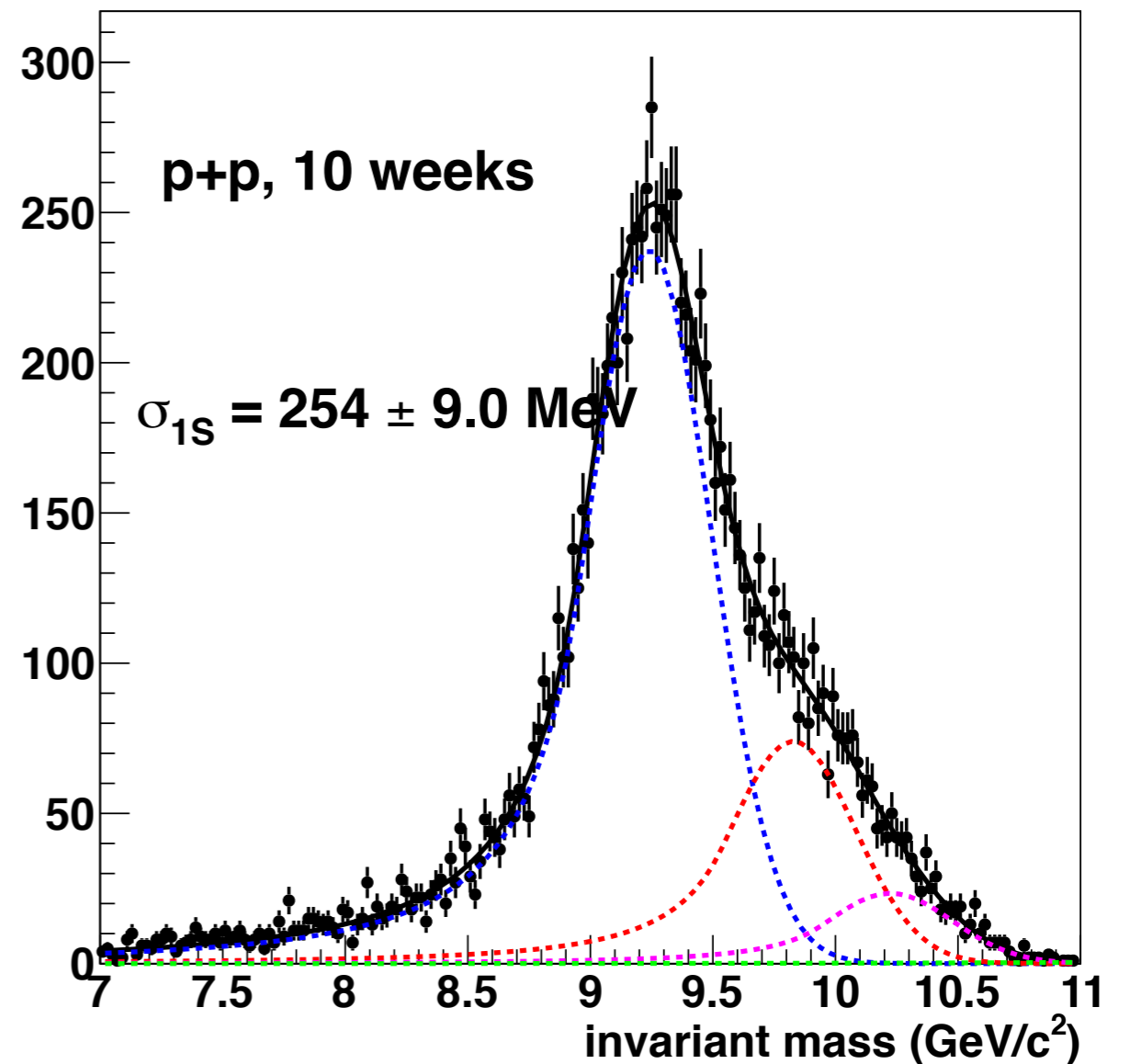
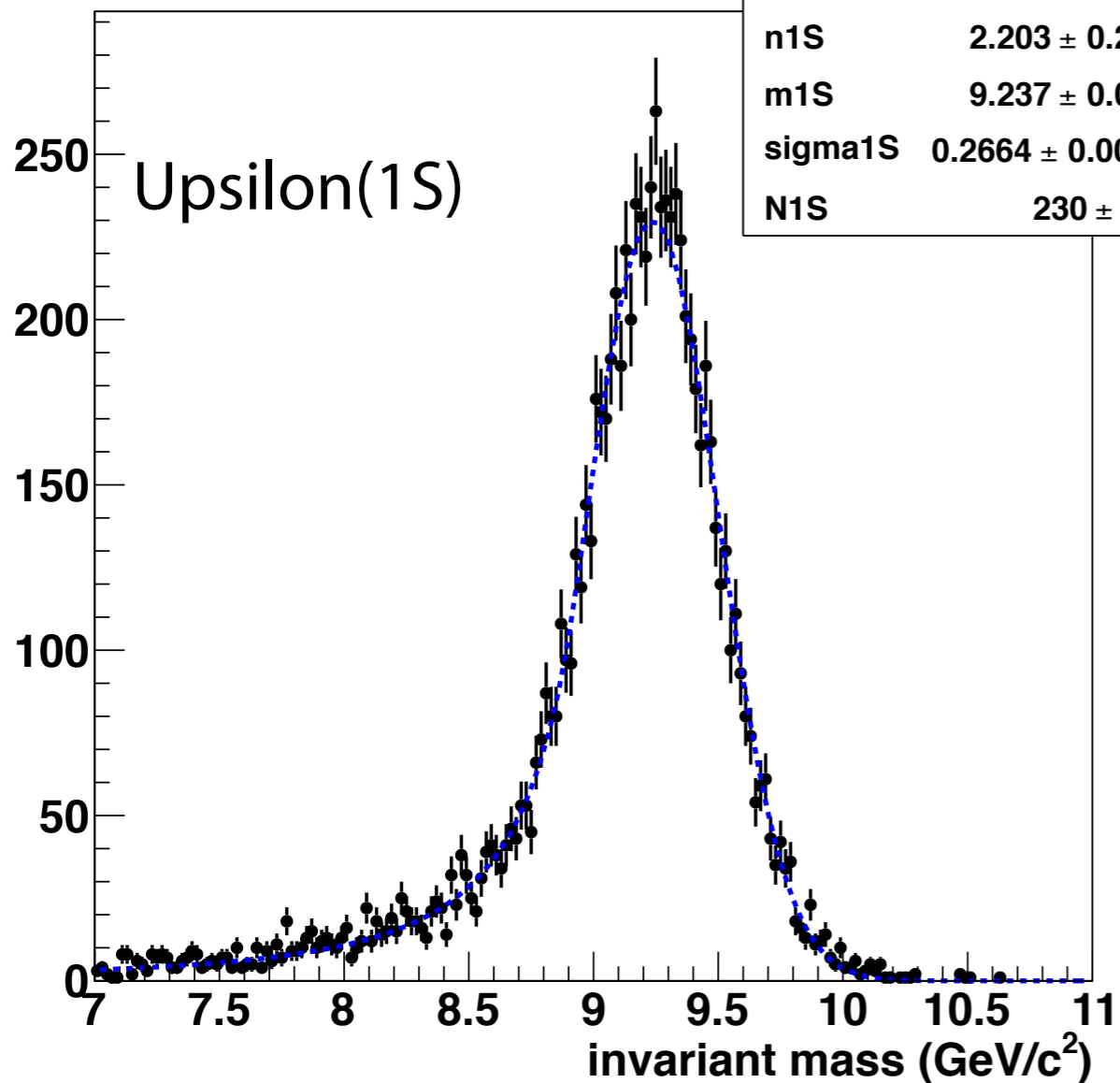
Tony's result was sigma  $\sim 94$  MeV/c.  
I got a better result, probably due to ganging off.

# Update design 1 (see page 2)



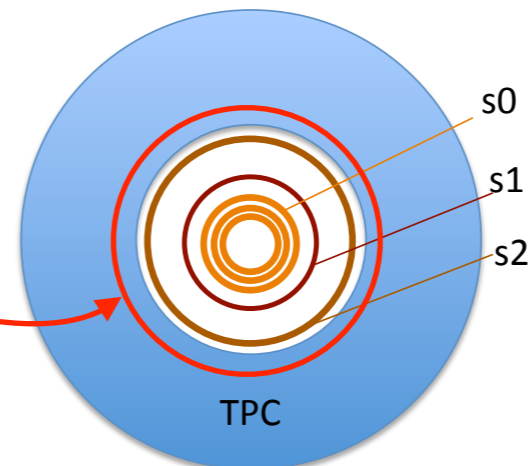
Station	R [cm]	$X_0$ [%]
(p0)	2.4	1.3
s0a	8	1.0
s0b	10	1.0
s0c	12	1.0
s1	15	0.6
s2	30	1.0

$Y(1S,2S,3S) \rightarrow e^+e^-$



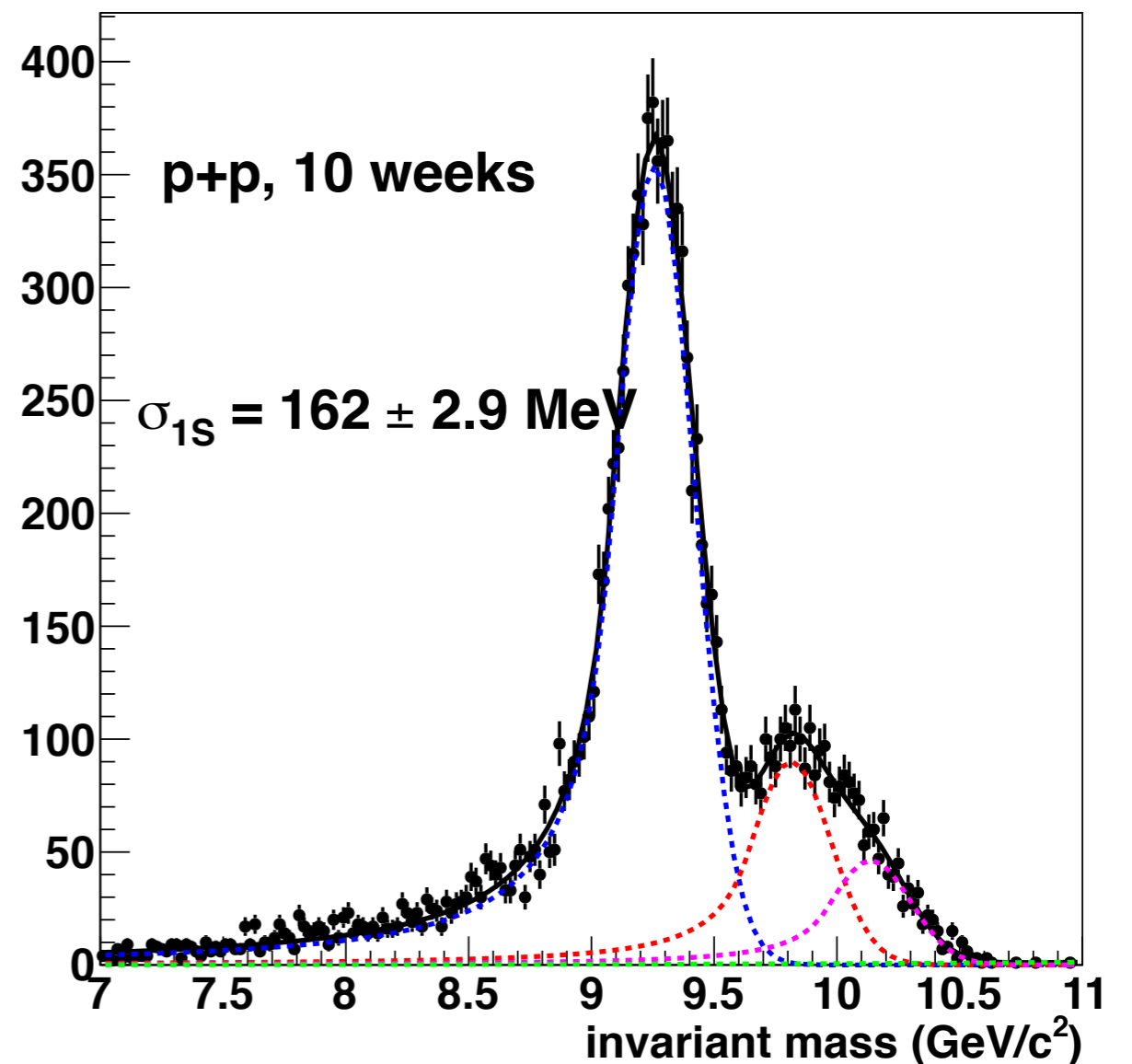
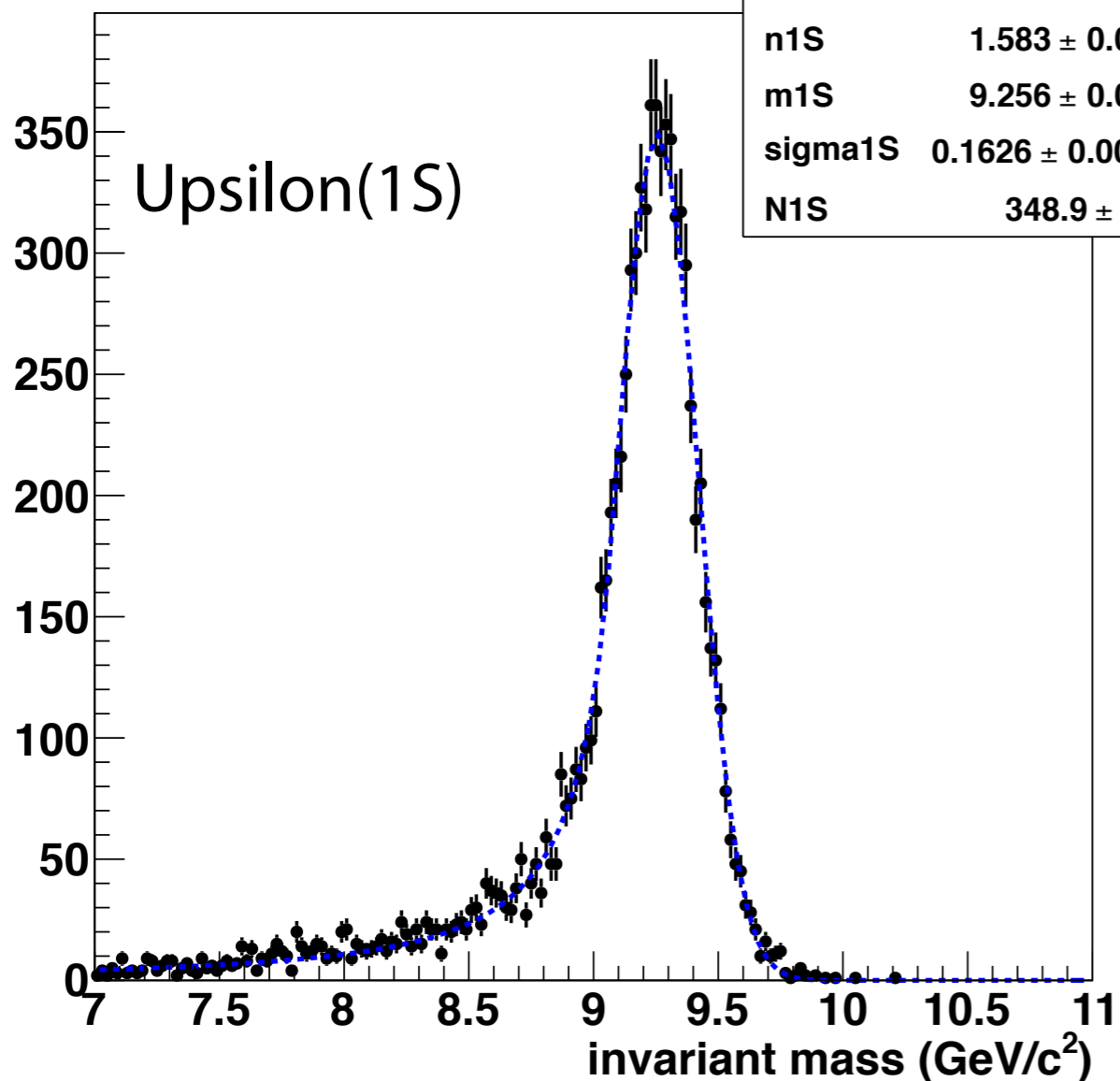
# Update design 2 (design 1 + one more S2)

Additional S2 layer (R=40cm)



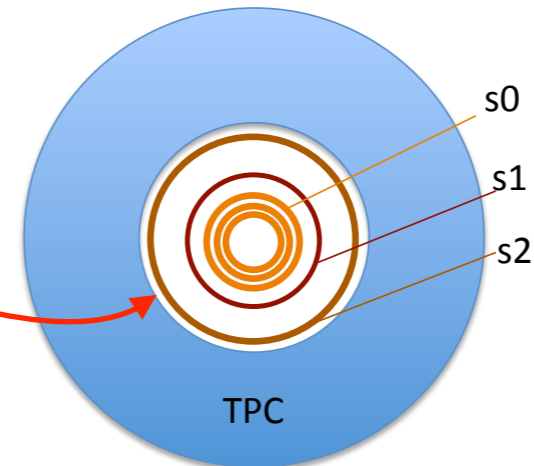
Station	R [cm]	$X_0$ [%]
(p0)	2.4	1.3
s0a	8	1.0
s0b	10	1.0
s0c	12	1.0
s1	15	0.6
s2	30	1.0
s2	40	1.0

$Y(1S,2S,3S) \rightarrow e^+e^-$



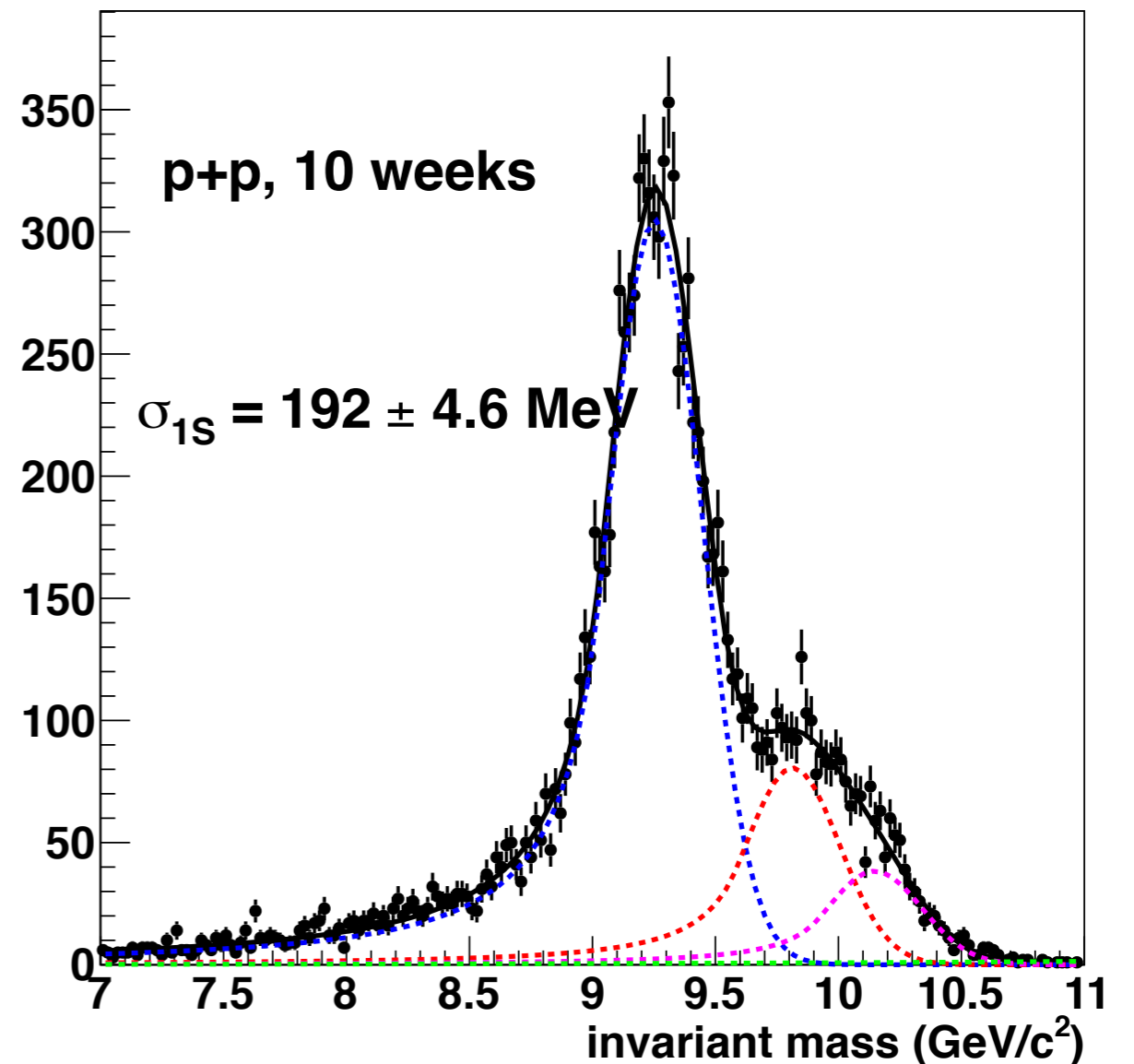
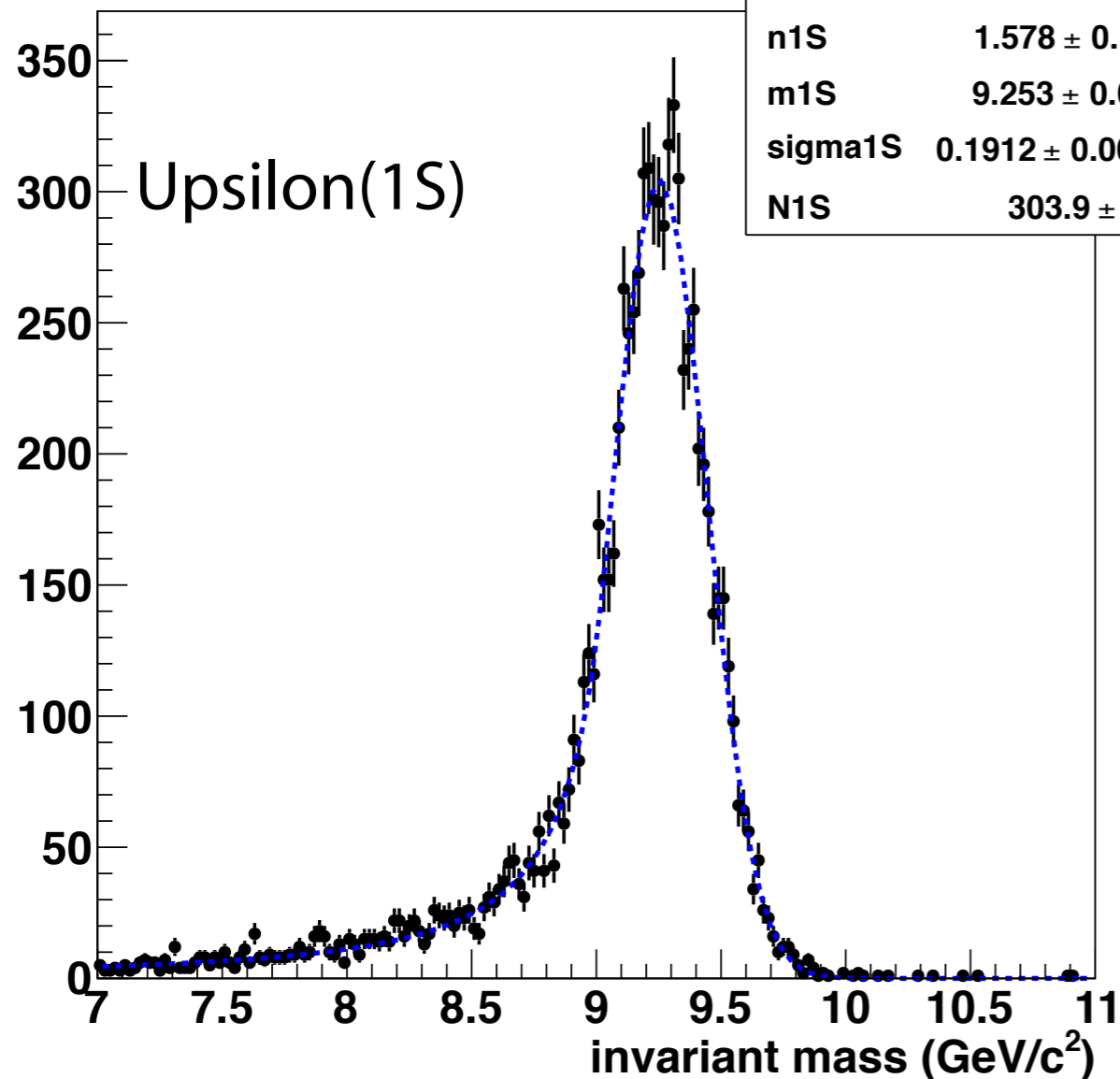
# Update design 3 (S2 moves to R=40cm)

S2 is moved to R=40cm



Station	R [cm]	$X_0$ [%]
(p0)	2.4	1.3
s0a	8	1.0
s0b	10	1.0
s0c	12	1.0
s1	15	0.6
s2	<del>30</del> 40	1.0

$Y(1S,2S,3S) \rightarrow e^+e^-$



# Summary

- Update design 2 looks acceptable once we get the pixel layer.
- But design 1 and 3 look hardly working once some systematic errors would be taken into account.
- Need more discussion and simulation.